NSN 5961-01-061-2045

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-061-2045 **Inclosure Material:** Glass **Overall Length:** 51.050 millimeters **Terminal Length:** 6.600 millimeters **Overall Diameter:** Between 0.315 inches and 0.335 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-39 **Mounting Method: Terminal Terminal Circle Diameter:** 9.390 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector to emitter, sustained and 80.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 2.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 8.0 milliwatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** Low frequency power silicon pnp bjt **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No